

## STTH200W06TV1

## Turbo 2 ultrafast high voltage rectifier

Datasheet - production data

#### **Features**

- Ultrafast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching and conduction losses
- Insulated package
  - Insulating voltage = 2500 V rms
  - Capacitance = 45 pF
- Complies with UL standards (File ref: E81734)

### **Description**

The STTH200W06TV1, which uses ST Turbo 2, 600 V technology, is especially suited to be used for DC/AC and DC/AC converters in primary stage of MIG/MMA/TIG welding machine.

Packaged in ISOTOP, this device offers high power integration for all welding machines and industrial equipment.

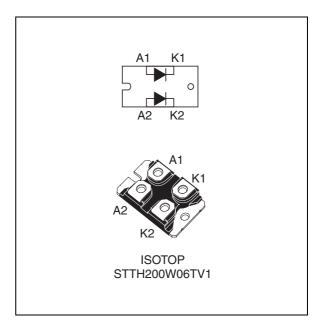


Table 1. Device summary

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Symbol	Value			
I <sub>F(AV)</sub>	2 x 100 A			
V <sub>RRM</sub>	600 V			
T <sub>j</sub> (max)	150 °C			
V <sub>F</sub> (typ)	1.0 V			
t <sub>rr</sub> (typ)	55 ns			

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#### 1 Characteristics

Table 2. Absolute ratings (limiting values at  $T_i = 25$  °C, unless otherwise specified, per diode)

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage		600	V
I <sub>F(RMS)</sub>	Forward rms current	Per diode	145	Α
I <sub>F(peak)</sub>	Average forward current, $\delta = 0.2$	Per diode T <sub>c</sub> = 105 °C	200	Α
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms Sinusoidal	800	Α
T <sub>stg</sub>	Storage temperature range		-65 to + 150	°C
Tj	Maximum operating junction temperature	150	°C	

Table 3. Thermal parameters

Symbol	Pa	Value	Unit	
В		Per diode	0.7	
R <sub>th(j-c)</sub> Junction to case	Total	0.4	°C/W	
R <sub>th(c)</sub>	Coupling		0.1	

When the two diodes 1 and 2 are used simultaneously:

 $\Delta T_{j}(\text{diode 1}) = P \text{ (diode 1) } X \text{ R}_{th(j\text{-}c)} \text{ (per diode)} + P \text{ (diode 2) } x \text{ R}_{th(c)}$ 

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
ı (1)	I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 25 °C	$V_R = V_{RRM}$	-		30	μА
'R`		T <sub>j</sub> = 125 °C		-	30	300	
	V (2) Forward valteers draw	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 100 A			1.5	
V <sub>F</sub> <sup>(2)</sup>		T <sub>j</sub> = 150 °C		-	1	1.3	V
V <sub>F</sub> <sup>(2)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 200 A	-		1.75	V	
		T <sub>j</sub> = 150 °C	IF = 200 A	-	1.25	1.60	

<sup>1.</sup> Pulse test:  $t_p$  = 5 ms,  $\delta$  < 2%

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To evaluate the conduction losses use the following equation:

$$P = 1.0 \text{ x } I_{F(AV)} + 0.003 \text{ x } I_{F}^{2}_{(RMS)}$$

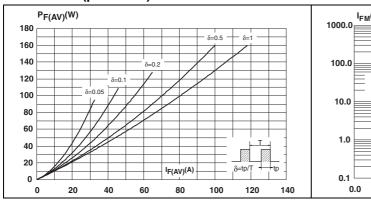
<sup>2.</sup> Pulse test:  $t_p$  = 380  $\mu$ s,  $\delta$  < 2%

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Table 5. Dynamic characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>RM</sub>	Reverse recovery current			-	30	40	Α
Q <sub>RR</sub>	Reverse recovery charge	T <sub>j</sub> = 125 °C	$I_F = 100 \text{ A}, V_R = 400 \text{ V}$ $dI_F/dt = -200 \text{ A/}\mu\text{s}$		4600		nC
S <sub>factor</sub>	Softness factor				0.4		
t <sub>rr</sub>	Reverse recovery time	T <sub>j</sub> = 25 °C	$I_F = 1 \text{ A}, V_R = 30 \text{ V}$ $dI_F/dt = -100 \text{ A/µs}$	-	55	75	ns
t <sub>fr</sub>	Forward recovery time	$T_j = 25 ^{\circ}\text{C}$ $I_F = 100 \text{A},  V_{FR} = 2.5 \text{V}$		-		2000	ns
V <sub>FP</sub>	Forward recovery voltage	T <sub>j</sub> = 25 °C	= 25 °C dI <sub>F</sub> /dt = 100 A/µs		3.3	5	V

Figure 1. Average forward power dissipation Figure 2. Forward voltage drop versus versus average forward current (per diode) (per diode)



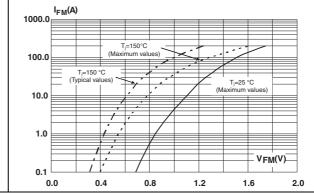
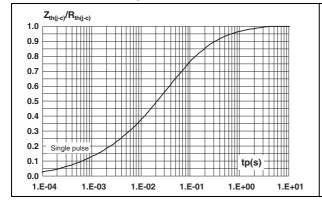
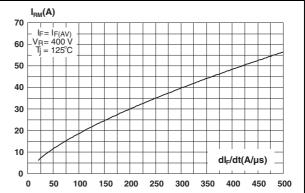


Figure 3. Relative variation of thermal impedance, junction to case, versus pulse duration

Figure 4. Peak reverse recovery current versus dl<sub>F</sub>/dt (typical values, per diode)





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Figure 5. Reverse recovery time versus dl<sub>F</sub>/dt Figure 6. Reverse recovery charges versus (typical values, per diode) dl<sub>F</sub>/dt (typical values, per diode)

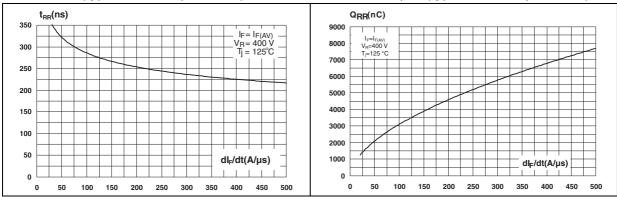


Figure 7. Reverse recovery softness factor versus dl<sub>F</sub>/dt (typical values, per diode)

Figure 8. Relative variation of dynamic parameters versus junction temperature

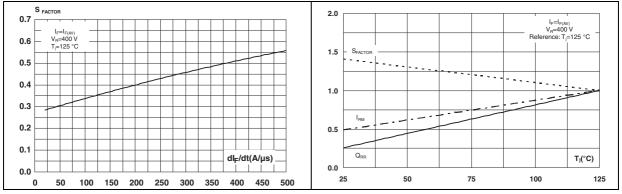
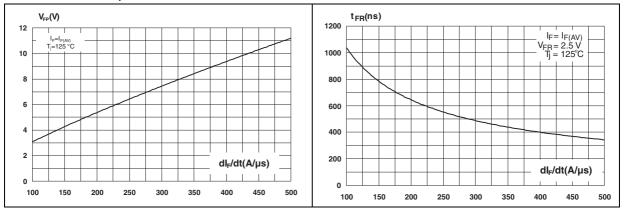


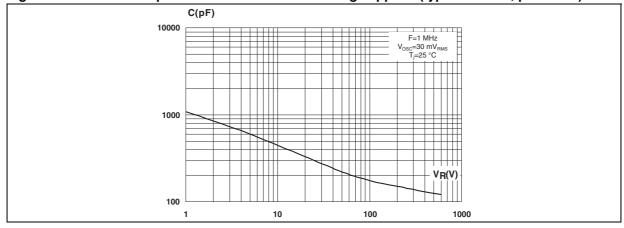
Figure 9. Transient peak forward voltage versus dl<sub>F</sub>/dt (typical values, per diode)

Figure 10. Forward recovery time versus dl<sub>F</sub>/dt (typical values, per diode)



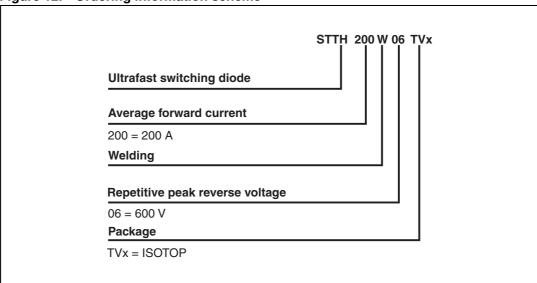
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Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)



# 2 Ordering information scheme

Figure 12. Ordering information scheme

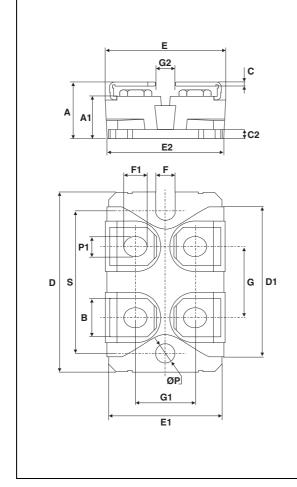


## 3 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 1.3 N⋅m (1.5 N⋅m maximum)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 6. ISOTOP dimensions



	Dimensions				
Ref.	Millimeters		Inc	hes	
	Min.	Max.	Min.	Max.	
Α	11.80	12.20	0.465	0.480	
A1	8.90	9.10	0.350	0.358	
В	7.8	8.20	0.307	0.323	
С	0.75	0.85	0.030	0.033	
C2	1.95	2.05	0.077	0.081	
D	37.80	38.20	1.488	1.504	
D1	31.50	31.70	1.240	1.248	
E	25.15	25.50	0.990	1.004	
E1	23.85	24.15	0.939	0.951	
E2	24.80 typ.		0.976 typ.		
G	14.90	15.10	0.587	0.594	
G1	12.60	12.80	0.496	0.504	
G2	3.50	4.30	0.138	0.169	
F	4.10	4.30	0.161	0.169	
F1	4.60	5.00	0.181	0.197	
Р	4.00	4.30	0.157	0.69	
P1	4.00	4.40	0.157	0.173	
S	30.10	30.30	1.185	1.193	

# 4 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty <sup>(1)</sup>	Delivery mode
STTH200W06TV1	STTH200W06TV1	ISOTOP	27 g	10 with screws	Tube

This product is supplied with 40 terminal screws and washers for each tube. The screws and washers are supplied in a separate pack with the order.

# 5 Revision history

Table 8. Document revision history

Date	Revision	Changes
05-Oct-2012	1	First issue

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